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# ***DISCRETE POWER DIODES and THYRISTORS***

## ***DATA BOOK***

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**To Order**

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## INVERTER GRADE THYRISTORS

## Hockey Puk Version

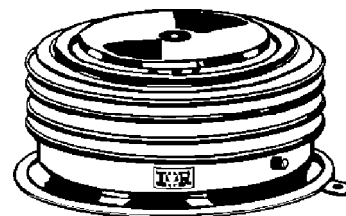
### Features

- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)
- All diffused design
- Center amplifying gate
- Guaranteed high dV/dt
- Guaranteed high dI/dt
- High surge current capability
- Low thermal impedance
- High speed performance

### Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

940A



case style TO-200AC (B-PUK)

### Major Ratings and Characteristics

| Parameters        | ST733C..L   | Units             |
|-------------------|-------------|-------------------|
| $I_{T(AV)}$       | 940         | A                 |
| @ $T_{hs}$        | 55          | °C                |
| $I_{T(RMS)}$      | 1900        | A                 |
| @ $T_{hs}$        | 25          | °C                |
| $I_{TSM}$ @ 50Hz  | 20000       | A                 |
| @ 60Hz            | 20950       | A                 |
| $I^2t$ @ 50Hz     | 2000        | KA <sup>2</sup> s |
| @ 60Hz            | 1820        | KA <sup>2</sup> s |
| $V_{DRM}/V_{RRM}$ | 400 to 800  | V                 |
| $t_q$ range       | 10 to 20    | μs                |
| $T_j$             | - 40 to 125 | °C                |

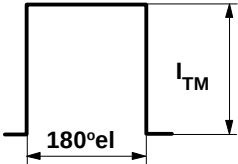
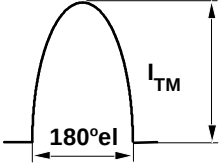
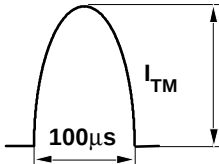
## ELECTRICAL SPECIFICATIONS



## Voltage Ratings

| Type number | Voltage Code | $V_{\text{DRM}}/V_{\text{RRM}}$ , maximum repetitive peak voltage<br>V | $V_{\text{RSM}}$ , maximum non-repetitive peak voltage<br>V | $I_{\text{DRM}}/I_{\text{RRM}}$ max.<br>@ $T_J = T_J$ max.<br>mA |
|-------------|--------------|------------------------------------------------------------------------|-------------------------------------------------------------|------------------------------------------------------------------|
| ST733C..L   | 04           | 400                                                                    | 500                                                         | 75                                                               |
|             | 08           | 800                                                                    | 900                                                         |                                                                  |

## Current Carrying Capability

| Frequency                        |  |      |  |      |  |      | Units |
|----------------------------------|-----------------------------------------------------------------------------------|------|------------------------------------------------------------------------------------|------|-------------------------------------------------------------------------------------|------|-------|
| 50Hz                             | 2200                                                                              | 1900 | 3580                                                                               | 3100 | 6800                                                                                | 5920 | A     |
| 400Hz                            | 2050                                                                              | 1660 | 3600                                                                               | 3130 | 3750                                                                                | 3240 |       |
| 1000Hz                           | 1370                                                                              | 1070 | 2900                                                                               | 2450 | 2120                                                                                | 1780 |       |
| 2500Hz                           | 500                                                                               | 370  | 1220                                                                               | 980  | 960                                                                                 | 770  |       |
| Recovery voltage Vr              | 50                                                                                | 50   | 50                                                                                 | 50   | 50                                                                                  | 50   | V     |
| Voltage before turn-on Vd        | V <sub>DRM</sub>                                                                  |      | V <sub>DRM</sub>                                                                   |      | V <sub>DRM</sub>                                                                    |      |       |
| Rise of on-state current di/dt   | 50                                                                                | 50   | -                                                                                  | -    | -                                                                                   | -    | A/µs  |
| Heatsink temperature             | 40                                                                                | 55   | 40                                                                                 | 55   | 40                                                                                  | 55   | °C    |
| Equivalent values for RC circuit | 10Ω / 0.47µF                                                                      |      | 10Ω / 0.47µF                                                                       |      | 10Ω / 0.47µF                                                                        |      |       |

## On-state Conduction

| Parameter           |                                                            | ST733C..L | Units              | Conditions                                                          |                       |                                                                          |
|---------------------|------------------------------------------------------------|-----------|--------------------|---------------------------------------------------------------------|-----------------------|--------------------------------------------------------------------------|
| I <sub>T(AV)</sub>  | Max. average on-state current<br>@ Heatsink temperature    | 940 (350) | A                  | 180° conduction, half sine wave<br>double side (single side) cooled |                       |                                                                          |
|                     |                                                            | 55 (85)   | °C                 |                                                                     |                       |                                                                          |
| I <sub>T(RMS)</sub> | Max. RMS on-state current                                  | 1900      | A                  | DC @ 25°C heatsink temperature double side cooled                   |                       |                                                                          |
| I <sub>TSM</sub>    | Max. peak, one half cycle,<br>non-repetitive surge current | 20000     |                    | t = 10ms                                                            | No voltage            | Sinusoidal half wave,<br><br>Initial T <sub>J</sub> = T <sub>J</sub> max |
|                     |                                                            | 20950     |                    | t = 8.3ms                                                           | reapplied             |                                                                          |
|                     |                                                            | 16800     |                    | t = 10ms                                                            | 100% V <sub>RRM</sub> |                                                                          |
|                     |                                                            | 17600     |                    | t = 8.3ms                                                           | reapplied             |                                                                          |
| I <sup>2</sup> t    | Maximum I <sup>2</sup> t for fusing                        | 2000      | KA <sup>2</sup> s  | t = 10ms                                                            | No voltage            |                                                                          |
|                     |                                                            | 1820      |                    | t = 8.3ms                                                           | reapplied             |                                                                          |
|                     |                                                            | 1410      |                    | t = 10ms                                                            | 100% V <sub>RRM</sub> |                                                                          |
|                     |                                                            | 1290      |                    | t = 8.3ms                                                           | reapplied             |                                                                          |
| I <sup>2</sup> √t   | Maximum I <sup>2</sup> √t for fusing                       | 20000     | KA <sup>2</sup> √s | t = 0.1 to 10ms, no voltage reapplied                               |                       |                                                                          |

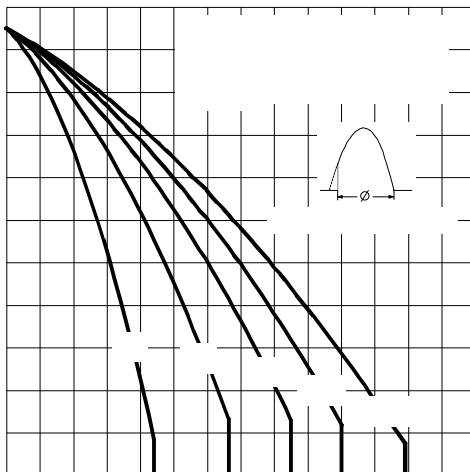


Fig. 3 - Current Ratings Characteristics

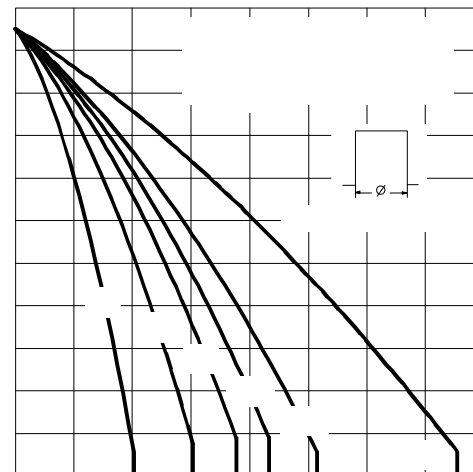


Fig. 4 - Current Ratings Characteristics

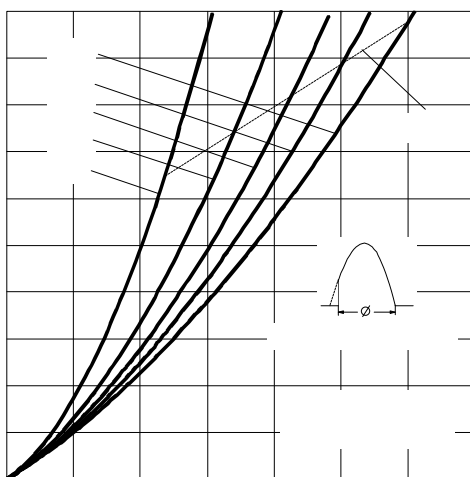


Fig. 5 - On-state Power Loss Characteristics

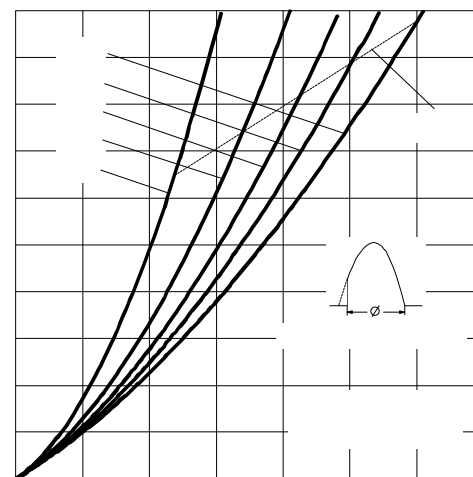


Fig. 6 - On-state Power Loss Characteristics

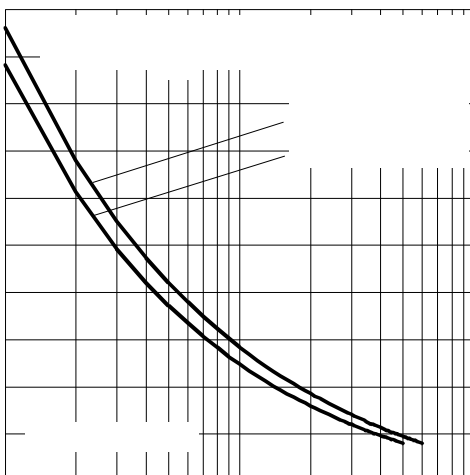


Fig. 7 - Maximum Non-repetitive Surge Current

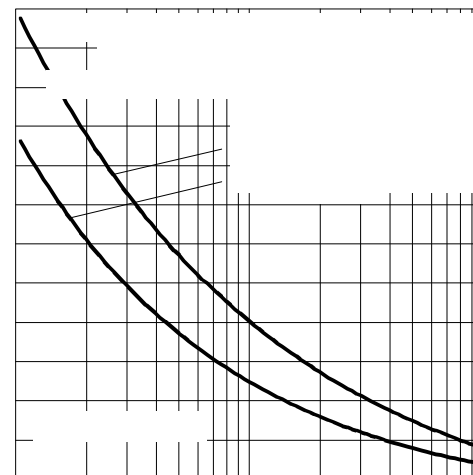


Fig. 8 - Maximum Non-repetitive Surge Current

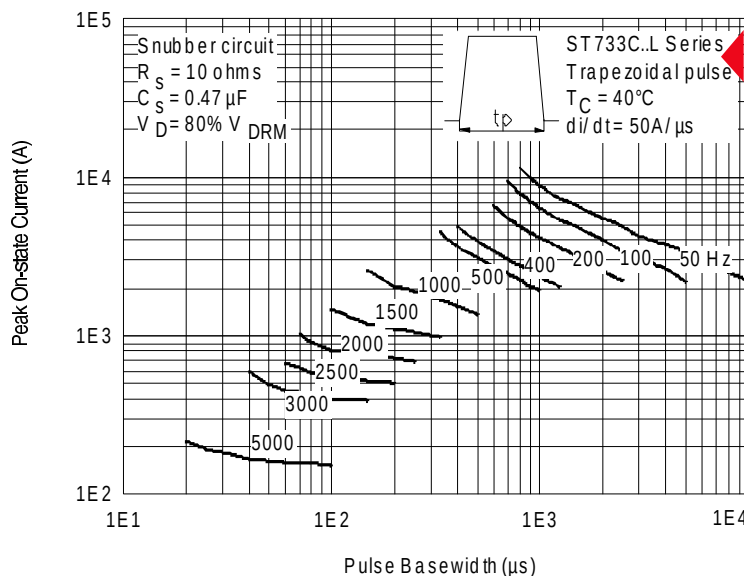
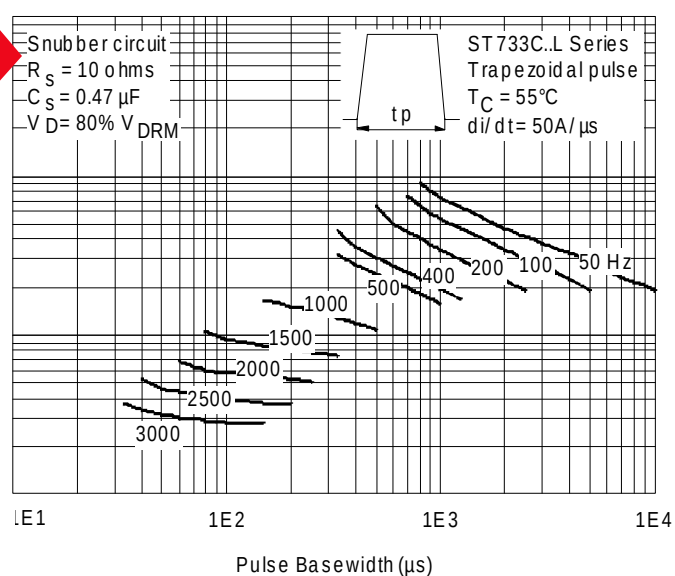


Fig. 14 - Frequency Characteristics

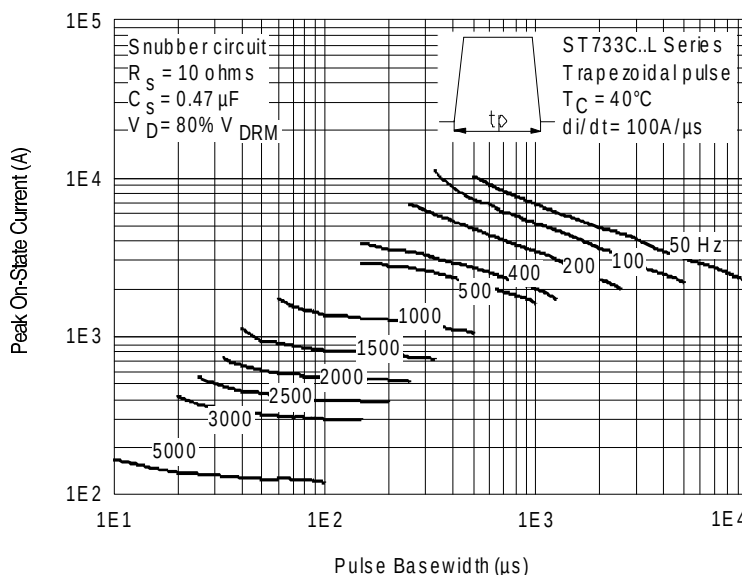
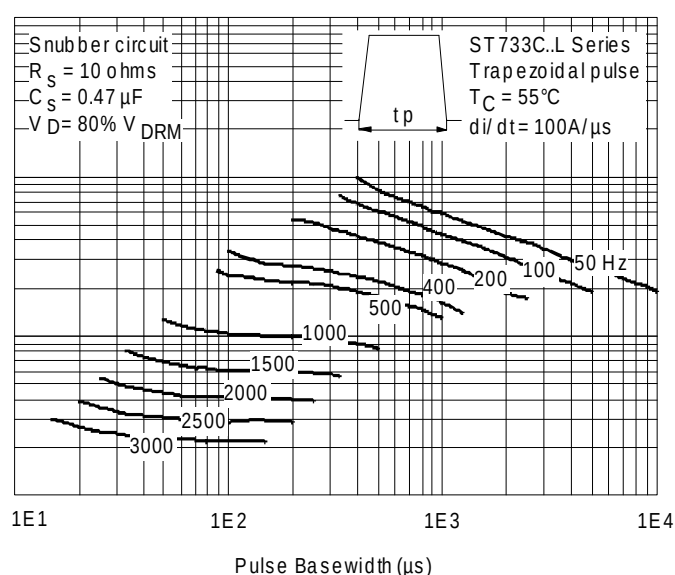


Fig. 15 - Frequency Characteristics

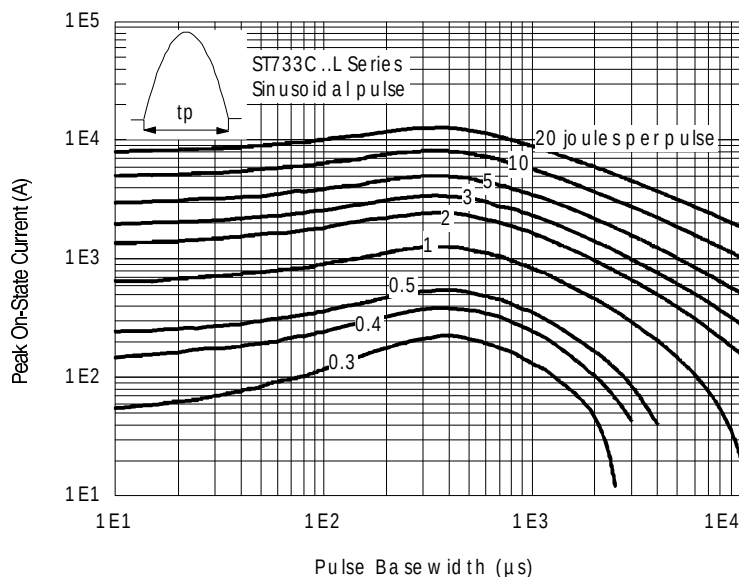
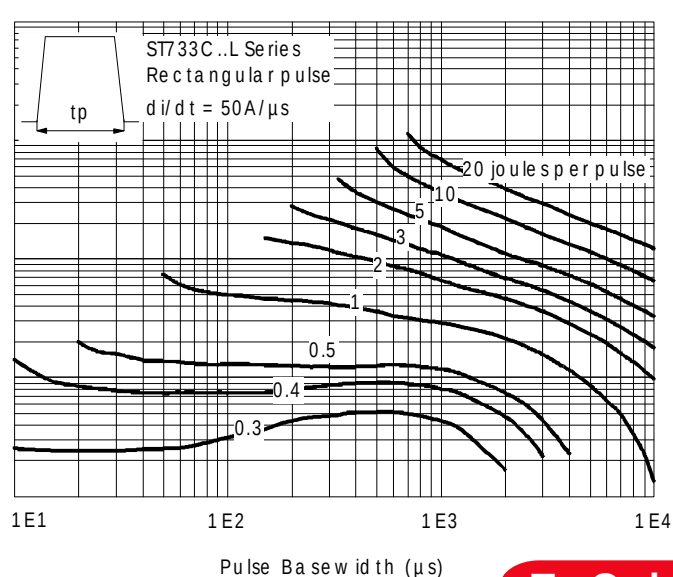


Fig. 16 - Maximum On-state Energy Power Loss Characteristics

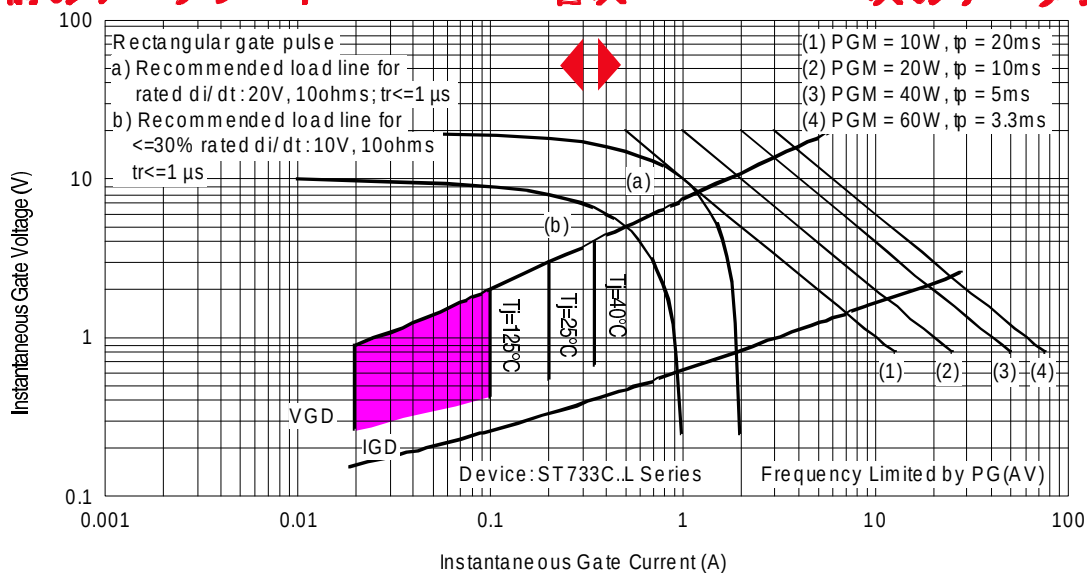


Fig. 17 - Gate Characteristics

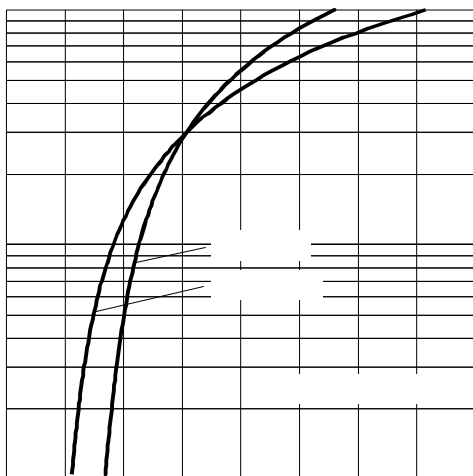


Fig. 9 - On-state Voltage Drop Characteristics

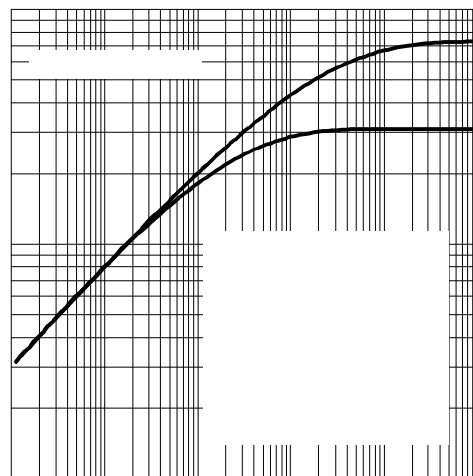
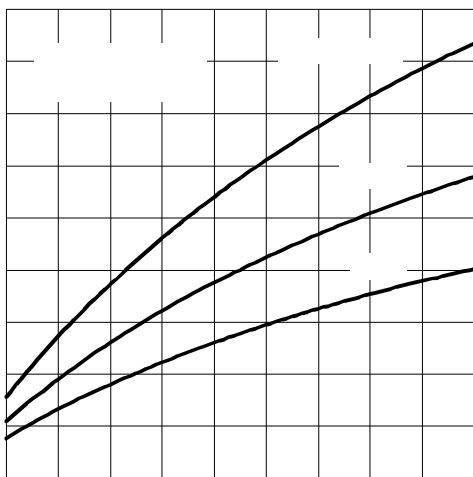
Fig. 10 - Thermal Impedance  $Z_{thJC}$  Characteristic

Fig. 11 - Reverse Recovered Charge Characteristics

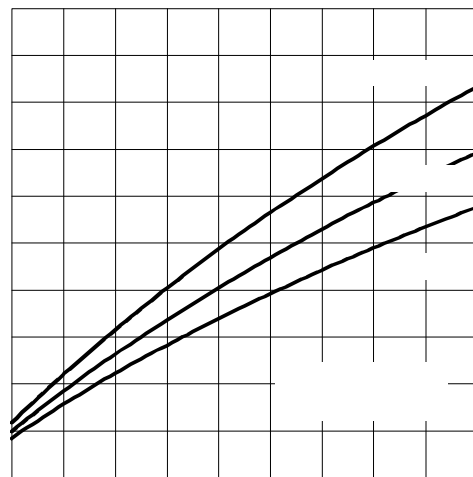


Fig. 12 - Reverse Recovery Current Characteristics

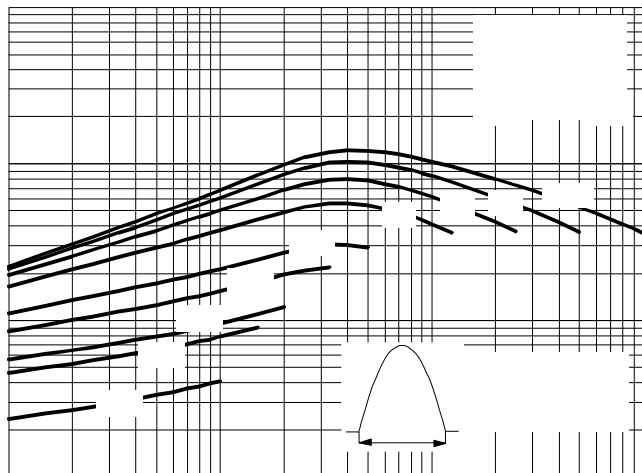
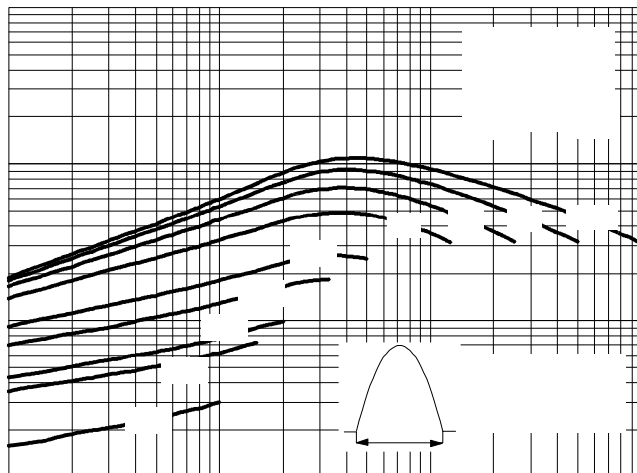


Fig. 13 - Frequency Characteristics

## On-state Conduction

| Parameter                                             | ST733C..L | Units | Conditions                                                                                    |
|-------------------------------------------------------|-----------|-------|-----------------------------------------------------------------------------------------------|
| $V_{TM}$ Max. peak on-state voltage                   | 1.63      | V     | $I_{TM} = 1700A$ , $T_J = T_J \text{ max}$ , $t_p = 10\text{ms}$ sine wave pulse              |
| $V_{T(To)1}$ Low level value of threshold voltage     | 1.09      |       | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ . |
| $V_{T(To)2}$ High level value of threshold voltage    | 1.20      |       | $(I > \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .                                      |
| $r_{t1}$ Low level value of forward slope resistance  | 0.32      | mΩ    | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ . |
| $r_{t2}$ High level value of forward slope resistance | 0.29      |       | $(I > \pi \times I_{T(AV)})$ , $T_J = T_J \text{ max}$ .                                      |
| $I_H$ Maximum holding current                         | 600       | mA    | $T_J = 25^\circ\text{C}$ , $I_T > 30A$                                                        |
| $I_L$ Typical latching current                        | 1000      |       | $T_J = 25^\circ\text{C}$ , $V_A = 12V$ , $R_a = 6\Omega$ , $I_G = 1A$                         |

## Switching

| Parameter                                                     | ST733C..L        | Units | Conditions                                                                                                                                                      |
|---------------------------------------------------------------|------------------|-------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $di/dt$ Max. non-repetitive rate of rise of turned-on current | 1000             | A/μs  | $T_J = T_J \text{ max}$ , $V_{DRM} = \text{rated } V_{DRM}$ , $I_{TM} = 2 \times di/dt$<br>Gate pulse: 20V 20Ω, 10μs 0.5μs rise time                            |
| $t_d$ Typical delay time                                      | 1.5              | μs    | $T_J = 25^\circ\text{C}$ , $V_{DM} = \text{rated } V_{DRM}$ , $I_{TM} = 50A \text{ DC}$ , $t_p = 1\mu\text{s}$<br>Resistive load, Gate pulse: 10V, 5Ω source    |
| $t_q$ Max. turn-off time                                      | Min 10<br>Max 20 |       | $T_J = T_J \text{ max}$ , $I_{TM} = 550A$ , commutating $di/dt = -40A/\mu\text{s}$<br>$V_R = 50V$ , $t_p = 500\mu\text{s}$ , $dv/dt$ : see table in device code |

## Blocking

| Parameter                                                  | ST733C..L | Units | Conditions                                                                            |
|------------------------------------------------------------|-----------|-------|---------------------------------------------------------------------------------------|
| $dv/dt$ Maximum critical rate of rise of off-state voltage | 500       | V/μs  | $T_J = T_J \text{ max}$ . linear to 80% $V_{DRM}$ , higher value available on request |
| $I_{RRM}$ Max. peak reverse and off-state leakage current  | 75        | mA    | $T_J = T_J \text{ max}$ , rated $V_{DRM}/V_{RRM}$ applied                             |

## Triggering

| Parameter                                         | ST733C..L | Units | Conditions                                                |
|---------------------------------------------------|-----------|-------|-----------------------------------------------------------|
| $P_{GM}$ Maximum peak gate power                  | 60        | W     | $T_J = T_J \text{ max.}$ , $f = 50\text{Hz}$ , $d\% = 50$ |
| $P_{G(AV)}$ Maximum average gate power            | 10        |       |                                                           |
| $I_{GM}$ Max. peak positive gate current          | 10        | A     | $T_J = T_J \text{ max}$ , $t_p \leq 5\text{ms}$           |
| $+V_{GM}$ Maximum peak positive gate voltage      | 20        | V     | $T_J = T_J \text{ max}$ , $t_p \leq 5\text{ms}$           |
| $-V_{GM}$ Maximum peak negative gate voltage      | 5         |       |                                                           |
| $I_{GT}$ Max. DC gate current required to trigger | 200       | mA    | $T_J = 25^\circ\text{C}$ , $V_A = 12V$ , $R_a = 6\Omega$  |
| $V_{GT}$ Max. DC gate voltage required to trigger | 3         | V     |                                                           |
| $I_{GD}$ Max. DC gate current not to trigger      | 20        | mA    | $T_J = T_J \text{ max}$ , rated $V_{DRM}$ applied         |
| $V_{GD}$ Max. DC gate voltage not to trigger      | 0.25      | V     |                                                           |

## Thermal and Mechanical Specification

| Parameter                                                     | ST733C..L          | Units     | Conditions                                                         |
|---------------------------------------------------------------|--------------------|-----------|--------------------------------------------------------------------|
| $T_J$ Max. operating temperature range                        | -40 to 125         | °C        |                                                                    |
| $T_{stg}$ Max. storage temperature range                      | -40 to 150         |           |                                                                    |
| $R_{thJ-hs}$ Max. thermal resistance,<br>junction to heatsink | 0.073<br>0.031     | K/W       | DC operation single side cooled<br>DC operation double side cooled |
| $R_{thC-hs}$ Max. thermal resistance,<br>case to heatsink     | 0.011<br>0.005     | K/W       | DC operation single side cooled<br>DC operation double side cooled |
| F Mounting force, $\pm 10\%$                                  | 14700<br>(1500)    | N<br>(Kg) |                                                                    |
| wt Approximate weight                                         | 255                | g         |                                                                    |
| Case style                                                    | TO - 200AC (B-PUK) |           | See Outline Table                                                  |

 $\Delta R_{thJ-hs}$  Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC)

| Conduction angle | Sinusoidal conduction |             | Rectangular conduction |             | Units | Conditions               |
|------------------|-----------------------|-------------|------------------------|-------------|-------|--------------------------|
|                  | Single Side           | Double Side | Single Side            | Double Side |       |                          |
| 180°             | 0.009                 | 0.009       | 0.006                  | 0.006       | K/W   | $T_J = T_J \text{ max.}$ |
| 120°             | 0.011                 | 0.011       | 0.011                  | 0.011       |       |                          |
| 90°              | 0.014                 | 0.014       | 0.015                  | 0.015       |       |                          |
| 60°              | 0.020                 | 0.021       | 0.021                  | 0.022       |       |                          |
| 30°              | 0.036                 | 0.036       | 0.036                  | 0.036       |       |                          |

## Ordering Information Table

## Device Code

|    |    |   |   |    |   |   |   |   |    |
|----|----|---|---|----|---|---|---|---|----|
| ST | 73 | 3 | C | 08 | L | H | K | 1 |    |
| 1  | 2  | 3 | 4 | 5  | 6 | 7 | 8 | 9 | 10 |

- 1** - Thyristor
- 2** - Essential part number
- 3** - 3 = Fast turn off
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 =  $V_{RRM}$  (See Voltage Rating Table)
- 6** - L = Puk Case TO-200AC (B-PUK)
- 7** - Reapplied dv/dt code (for  $t_q$  test condition)
- 8** -  $t_q$  code
- 9** - 0 = Eyelet term. (Gate and Aux. Cathode Unsoldered Leads)  
1 = Fast-on term. (Gate and Aux. Cathode Unsoldered Leads)  
2 = Eyelet term. (Gate and Aux. Cathode Soldered Leads)  
3 = Fast-on term. (Gate and Aux. Cathode Soldered Leads)
- 10** - Critical dv/dt:  
None = 500V/ $\mu$ sec (Standard value)  
L = 1000V/ $\mu$ sec (Special selection)

| dv/dt - $t_q$ combinations available |    |    |     |             |     |
|--------------------------------------|----|----|-----|-------------|-----|
| dv/dt (V/ $\mu$ s)                   | 20 | 50 | 100 | 200         | 400 |
| 10                                   | CN | DN | EN  | --          | --  |
| 12                                   | CM | DM | EM  | <b>FM *</b> | --  |
| 15                                   | CL | DL | EL  | <b>FL *</b> | HL  |
| 18                                   | CP | DP | EP  | FP          | HP  |
| 20                                   | CK | DK | EK  | FK          | H   |

\* Standard part number.

All other types available only on request.

To Order

ご注文

## Outline Table

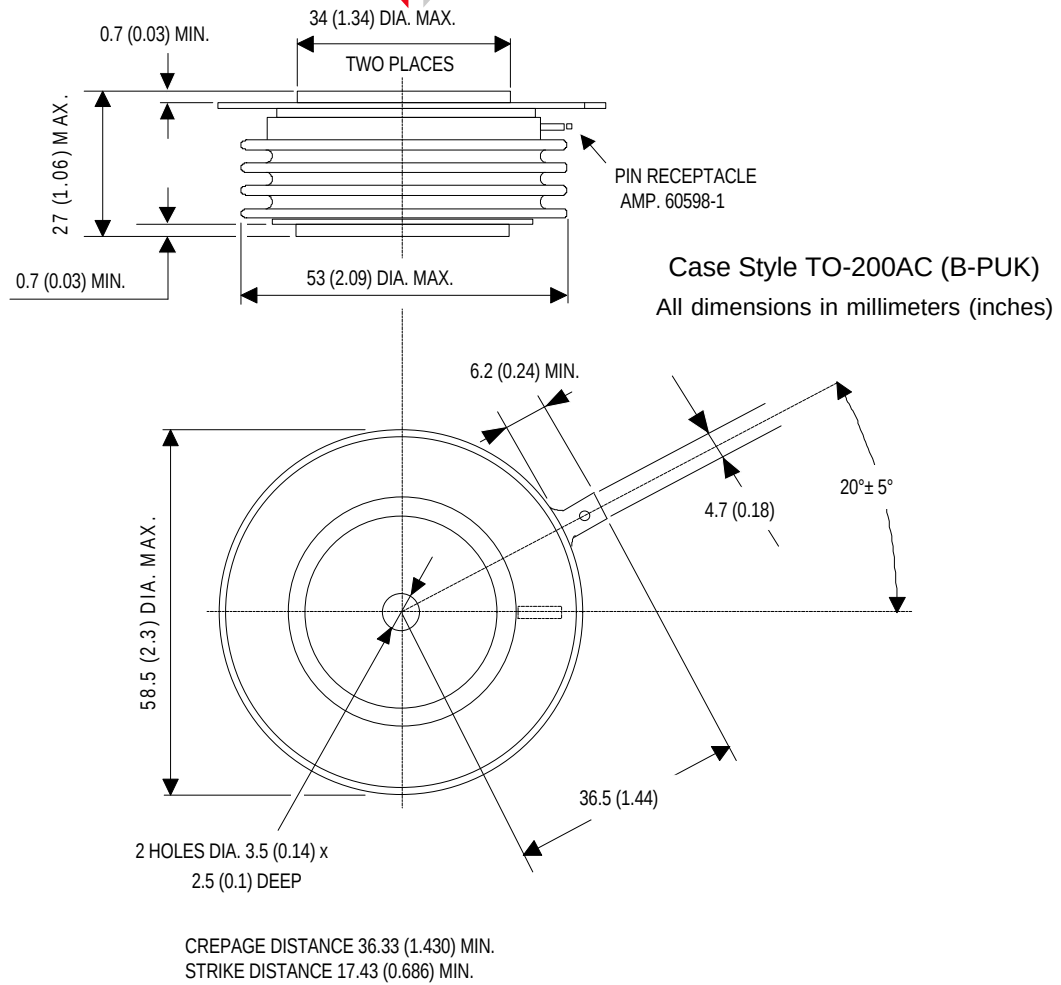
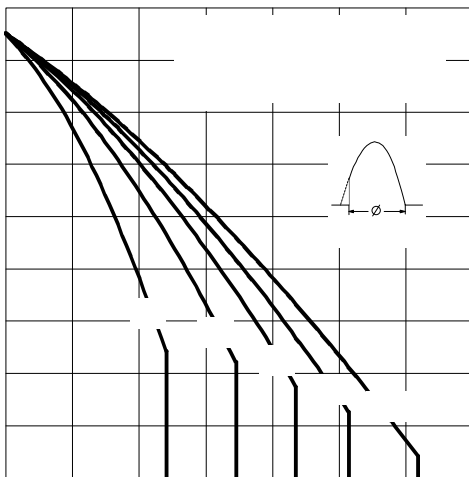


Fig. 1 - Current Ratings Characteristics

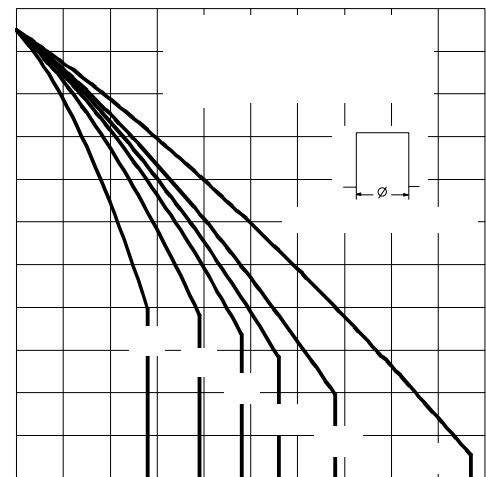


Fig. 2 - Current Ratings Characteristics